

EAST Search History

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|--|---|------------------|---------|------------------|
| S1 | 3176 | (257/328-334).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/09/26 14:59 |
| S2 | 2758 | S1 and (@ad<="20030724" or @rlad<="20030724") | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/09/26 14:59 |
| S3 | 801 | (hoshino-takashi harada-shin fujikwa-kazuhiro hatsukawa-satoshi hirotzu-kenichi).in. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/09/26 14:56 |
| S4 | 56 | S3 and transistor | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/09/11 15:27 |
| S5 | 2 | ("20010024138").PN. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/09/11 12:19 |
| S6 | 4 | "522278".ap. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/09/11 15:27 |
| S7 | 99 | "vertical junction field effect transistor" | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/09/26 14:56 |
| S8 | 76 | S7 and (@ad<="20030724" or @rlad<="20030724") | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/09/26 14:56 |

EAST Search History

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|-----|-----|--|---|----|-----|------------------|
| S9 | 709 | (257/302).CCLS. | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2006/09/26 14:59 |
| S10 | 644 | S9 and (@ad<="20030724" or @rlad<="20030724") | US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2006/09/26 14:59 |

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| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|--|----------|------------------|---------|------------------|
| L1 | 32 | (drift and buried and gate and channel and semiconductor).clm. | US-PGPUB | OR | ON | 2006/09/26 16:52 |